

# **800V N-Channel MOSFET**

### FEATURES

- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

### APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

Device Marking and Package Information			
Device Package		Marking	
CS7N80F	TO-220F	CS7N80F	
CS7N80P	TO-220	CS7N80P	

TO-220F GDS	TO-220 GDS
	Go

<b>Absolute Maximum Ratings</b> $T_c = 25^{\circ}C$ , unless otherwise noted					
Parameter	Symbol	Vá	Unit		
Farameter		TO-220F	TO-220	Unit	
Drain-Source Voltage ( $V_{GS} = 0V$ )	V <sub>DSS</sub>	800		V	
Continuous Drain Current	I <sub>D</sub>	7		А	
Pulsed Drain Current (note1)	I <sub>DM</sub>	28		А	
Gate-Source Voltage	V <sub>GSS</sub>	±	30	V	
Single Pulse Avalanche Energy (note2)	E <sub>AS</sub>	245		mJ	
Avalanche Current (note1)	I <sub>AS</sub>	7		А	
Repetitive Avalanche Energy (note1)	E <sub>AR</sub>	147		mJ	
Power Dissipation ( $T_c = 25^{\circ}C$ )	P <sub>D</sub>	25	70	W	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55-	-+150	°C	

Thermal Resistance				
Parameter	Symbol	Va	Unit	
		TO-220F	TO-220	- Unit
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	5	1.78	K/W
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	62.5	60	



# CS7N80F, CS7N80P

			Value				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V, I_{D} = 250 \mu A$	800			V	
Zero Gate Voltage Drain Current	1	$V_{DS} = 800V, V_{GS} = 0V, T_{J} = 25^{\circ}C$	-		1		
Zero Gale voltage Drain Gurrent	I <sub>DSS</sub>	$V_{DS} = 640V, V_{GS} = 0V, T_{J} = 125^{\circ}C$	-		100	μA	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{GS}$ = $\pm 30V$			±100	nA	
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.0		4.0	V	
Drain-Source On-Resistance (Note3)	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 3.5A$		1.35	1.6	Ω	
Dynamic							
Input Capacitance	C <sub>iss</sub>			1178			
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0V,$ $V_{DS} = 25V,$		128		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0MHz		27			
Total Gate Charge	$Q_{g}$			49			
Gate-Source Charge	$Q_gs$	$V_{DD} = 640V, I_D = 7A, V_{GS} = 10V$		6		nC	
Gate-Drain Charge	$Q_{gd}$			26			
Turn-on Delay Time	t <sub>d(on)</sub>			43			
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> = 400V, I <sub>D</sub> = 7A,		28			
Turn-off Delay Time	t <sub>d(off)</sub>	$R_{G} = 25 \Omega$		244		ns	
Turn-off Fall Time	t <sub>f</sub>			54			
Drain-Source Body Diode Character	istics						
Continuous Body Diode Current	۱ <sub>s</sub>	T 0500			7	۸	
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>C</sub> = 25 °C			28	A	
Body Diode Voltage	$V_{SD}$	$T_J = 25^{o}C, I_{SD} = 3.5A, V_{GS} = 0V$			1.4	V	
Reverse Recovery Time	t <sub>rr</sub>	V <sub>GS</sub> = 0V,I <sub>S</sub> = 7A,		295		ns	
Reverse Recovery Charge	Q <sub>rr</sub>	di <sub>F</sub> /dt =100A /µs		1.7		μC	

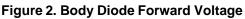
#### Notes

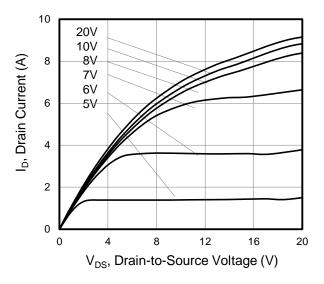
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature
- 2. L=10mH,  $V_{DD}$  = 50V,  $R_G$  = 25  $\Omega$ , Starting  $T_J$  = 25 °C
- 3. Pulse Test: Pulse width  $\leq$  300µs, Duty Cycle  $\leq$  1%



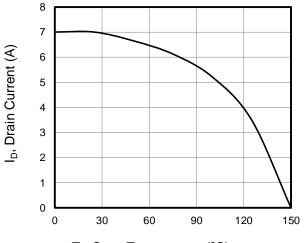
## **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted

Figure 1. Output Characteristics ( $T_J = 25^{\circ}C$ )

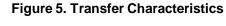


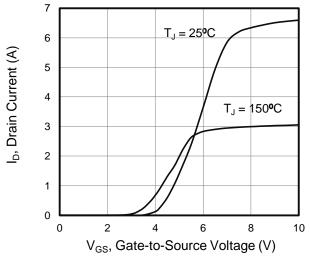






T<sub>J</sub>, Case Temperature (<sup>o</sup>C)





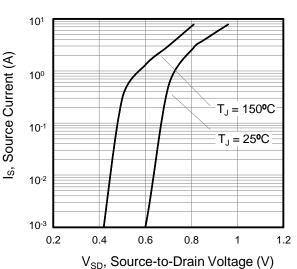


Figure 4. BV<sub>DSS</sub> Variation vs. Temperature

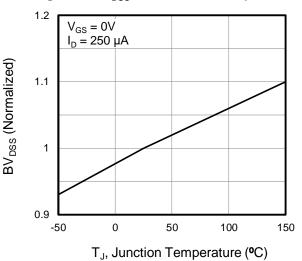
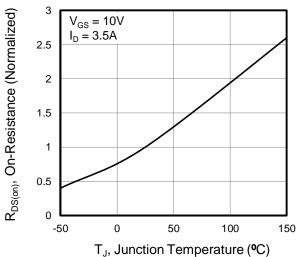
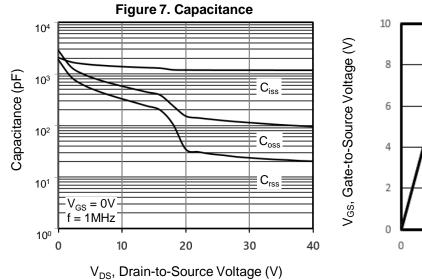


Figure 6. On-Resistance vs. Temperature

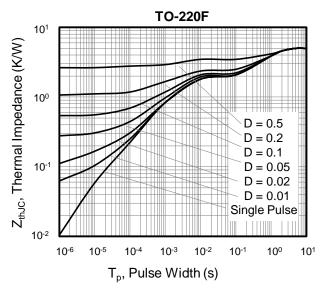




## **Typical Characteristics** $T_J = 25^{\circ}C$ , unless otherwise noted







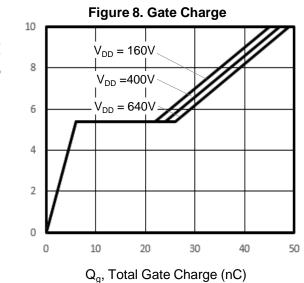
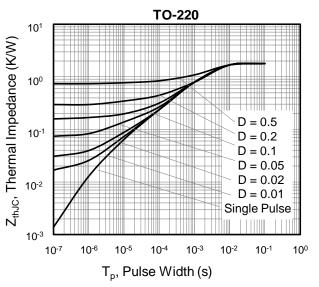


Figure 10. Transient Thermal Impedance







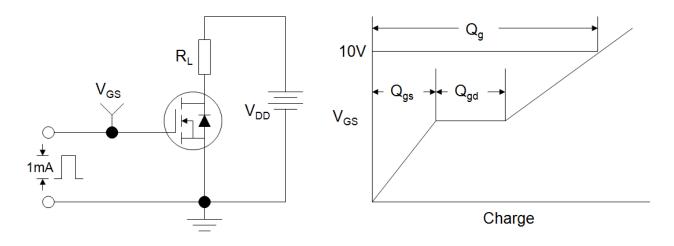


Figure B: Resistive Switching Test Circuit and Waveform

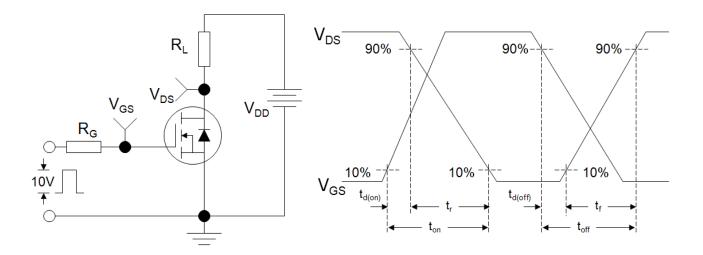
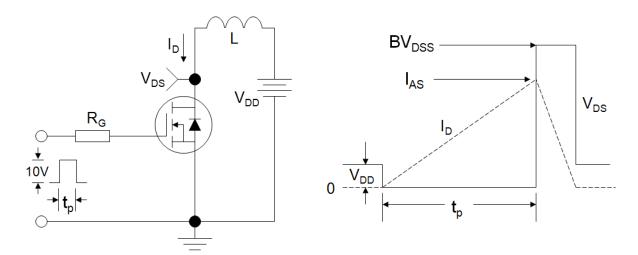


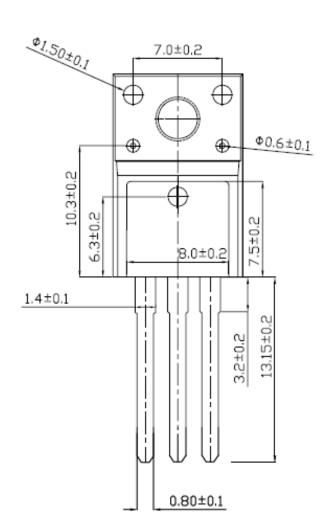
Figure C: Unclamped Inductive Switching Test Circuit and Waveform

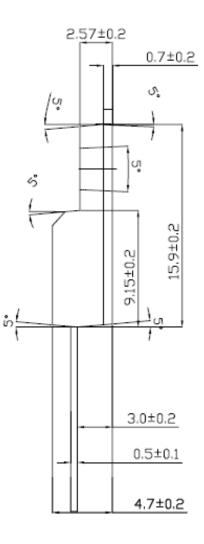






TO-220F

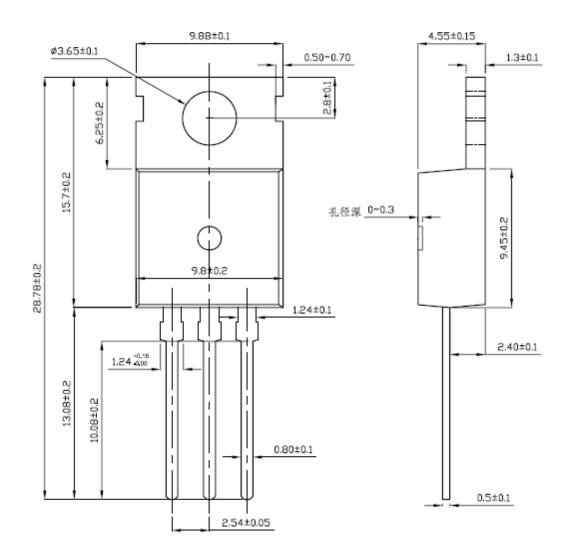








**TO-220** 





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